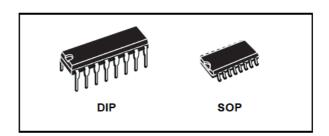




## DECADE COUNTER WITH 10 DECODED OUTPUTS

- MEDIUM SPEED OPERATION: 10 MHz (Typ.) at V<sub>DD</sub> = 10V
- FULLY STATIC OPERATION
- STANDARDIZED SYMMETRICAL OUTPUT CHARACTERISTICS
- QUIESCENT CURRENT SPECIFIED UP TO 20V
- 5V. 10V AND 15V PARAMETRIC RATINGS
- INPUT LEAKAGE CURRENT I<sub>I</sub> = 100nA (MAX) AT V<sub>DD</sub> = 18V T<sub>A</sub> = 25°C
- 100% TESTED FOR QUIESCENT CURRENT
- MEETS ALL REQUIREMENTS OF JEDEC JESD13B " STANDARD SPECIFICATIONS FOR DESCRIPTION OF B SERIES CMOS DEVICES"



#### **ORDER CODES**

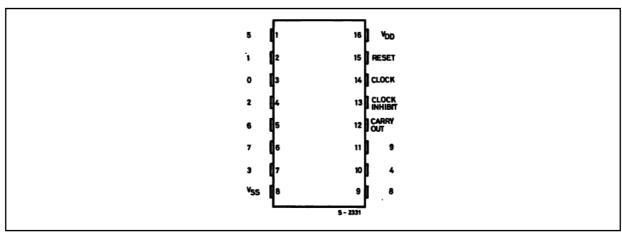
PACKAGE	TUBE	T&R
DIP	HCF4017BEY	
SOP	HCF4017BM1	HCF4017M013TR

#### **DESCRIPTION**

The HCF4017B is a monolithic integrated circuit fabricated in Metal Oxide Semiconductor technology available in DIP and SOP packages. The HCF4017B is 5-stage Johnson counter having 10 decoded outputs. Inputs include a CLOCK, a RESET, and a CLOCK INHIBIT signal. Schmitt trigger action in the clock input circuit provides pulse shaping that allows unlimited clock input pulse rise and fall times. This counter is advanced one count at the positive clock signal transition if the CLOCK INHIBIT signal is low. Counter advanced via the clock line is inhibited

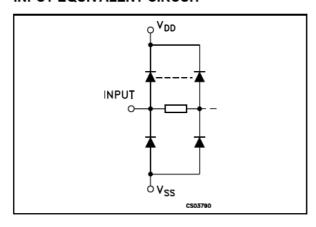
when the CLOCK INHIBIT signal is high. A high RESET signal clears the counter to its zero count. Use of the Johnson decade-counter configuration permits high speed operation, 2-input decimal decode gating and spike-free decoded outputs. Anti-lock gating is provided, thus assuring proper counting sequence. The decoded outputs are normally low and go high only at their respective decoded time slot. Each decoded output remains high for one full clock cycle. A CARRY - OUT signal completes one cycle every 10 clock input cycles and is used to ripple-clock the succeeding device in a multi-device counting chain.

#### **PIN CONNECTION**



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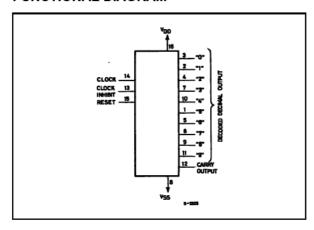
## **INPUT EQUIVALENT CIRCUIT**



## **PIN DESCRIPTION**

PIN No	SYMBOL	NAME AND FUNCTION
3, 2, 4, 7, 10, 1, 5, 6, 9, 11	0 to 9	Decoded Decimal Output
14	CLOCK	Clock Input
13	CLOCK INHIBIT	Clock Inhibit Input
15	RESET	Reset Input
12	CARRY OUT	Carry Output
8	V <sub>SS</sub>	Negative Supply Voltage
16	$V_{DD}$	Positive Supply Voltage

## **FUNCTIONAL DIAGRAM**

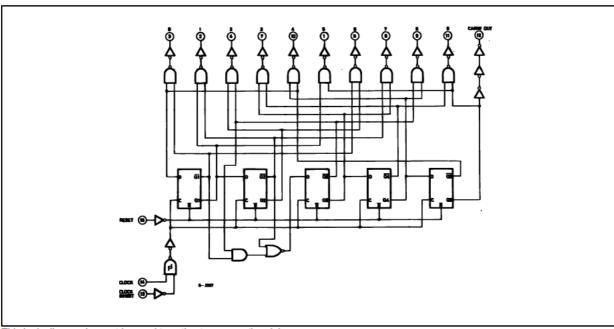


## **TRUTH TABLE**

сьоск	CLOCK INHIBIT	RESET	DECODED OUTPUT
Х	Х	Н	$Q_0$
L	X	L	Q <sub>n</sub>
Х	Н	L	Q <sub>n</sub>
Ч	L	L	Q <sub>n+1</sub>
L	L	L	Q <sub>n</sub>
Н	7	L	Q <sub>n</sub>
Н	l	L	Q <sub>n+1</sub>

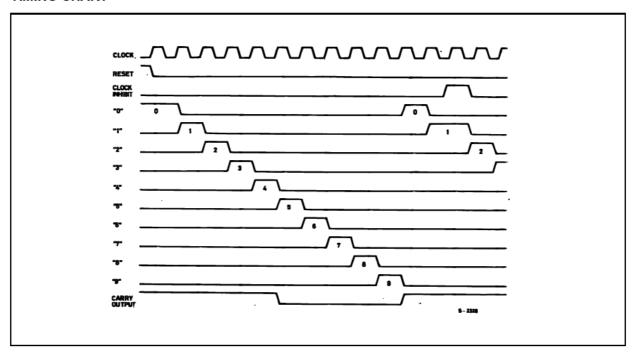
X : Don't Care Qn : No Change

## **LOGIC DIAGRAM**



This logic diagram has not be used to estimate propagation delays

#### **TIMING CHART**



### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	-0.5 to +22	V
٧ <sub>I</sub>	DC Input Voltage	-0.5 to V <sub>DD</sub> + 0.5	V
I <sub>I</sub>	DC Input Current	± 10	mA
$P_{D}$	Power Dissipation per Package	200	mW
	Power Dissipation per Output Transistor	100	mW
T <sub>op</sub>	Operating Temperature	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

All voltage values are referred to V<sub>SS</sub> pin voltage.

### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{DD}$	Supply Voltage	3 to 20	V
VI	Input Voltage	0 to V <sub>DD</sub>	V
T <sub>op</sub>	Operating Temperature	-55 to 125	°C

## DC SPECIFICATIONS

			Test Condition						Value				
Symbol Parameter		VI	v <sub>o</sub>	llol	V <sub>DD</sub>	T <sub>A</sub> = 25°C		С	-40 to 85°C		-55 to 125°C		Unit
		(V)	(V)	(μ <b>A</b> )	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
ΙL	Quiescent Current	0/5			5		0.04	5		150		150	
		0/10			10		0.04	10		300		300	μА
		0/15			15		0.04	20		600		600	μΑ
		0/20			20		0.08	100		3000		3000	
V <sub>OH</sub>	High Level Output	0/5		<1	5	4.95			4.95		4.95		
	Voltage	0/10		<1	10	9.95			9.95		9.95		V
		0/15		<1	15	14.95			14.95		14.95		
$V_{OL}$	V <sub>OL</sub> Low Level Output	5/0		<1	5		0.05			0.05		0.05	
	Voltage	10/0		<1	10		0.05			0.05		0.05	V
		15/0		<1	15		0.05			0.05		0.05	
$V_{IH}$	High Level Input		0.5/4.5	<1	5	3.5			3.5		3.5		V
	Voltage		1/9	<1	10	7			7		7		
			1.5/13.5	<1	15	11			11		11		
$\vee_{IL}$	Low Level Input		4.5/0.5	<1	5			1.5		1.5		1.5	
	Voltage		9/1	<1	10			3		3		3	V
			13.5/1.5	<1	15			4		4		4	
I <sub>OH</sub>	Output Drive	0/5	2.5	<1	5	-1.36	-3.2		-1.1		-1.1		
	Current	0/5	4.6	<1	5	-0.44	-1		-0.36		-0.36		mA
		0/10	9.5	<1	10	-1.1	-2.6		-0.9		-0.9		ША
		0/15	13.5	<b>&lt;</b> 1	15	-3.0	-6.8		-2.4		-2.4		
I <sub>OL</sub>	I <sub>OL</sub> Output Sink Current	0/5	0.4	<1	5	0.44	1		0.36		0.36		
		0/10	0.5	<1	10	1.1	2.6		0.9		0.9		mΑ
		0/15	1.5	<1	15	3.0	6.8		2.4		2.4		
l <sub>l</sub>	Input Leakage Current	0/18	Any In	put	18		±10 <sup>-5</sup>	±0.1		±1		±1	μΑ
CI	Input Capacitance		Any In	put			5	7.5					pF

The Noise Margin for both "1" and "0" level is: 1V min. with  $V_{DD}$ =5V, 2V min. with  $V_{DD}$ =10V, 2.5V min. with  $V_{DD}$ =15V

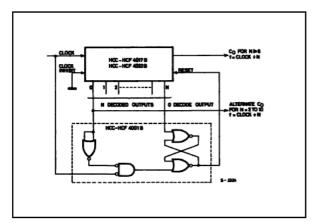
# $\textbf{DYNAMIC ELECTRICAL CHARACTERISTICS} \ (\textbf{T}_{amb} = 25 ^{\circ} \textbf{C}, \ \textbf{C}_{L} = 50 \text{pF}, \ \textbf{R}_{L} = 200 \text{K}\Omega, \ \textbf{t}_{f} = \textbf{t}_{f} = 20 \ \text{ns})$

Symbol	_		,	Value (*)			
Symbol	Parameter	V <sub>DD</sub> (V)		Min.	Тур.	Max.	
CLOCKE	OPERATION						
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time	5			325	650	
	(decode out)	10			135	270	ns
		15			85	170	
	Propagation Delay Time	5			300	600	
	(carry out)	10			125	250	ns
		15			80	160	
t <sub>THL</sub> t <sub>TLH</sub>	Transition Time (carry out	5			100	200	
	or decoded out lines)	10			50	100	ns
		15			40	80	
f <sub>CL</sub> (1)	Maximum Clock Input	5		2.5	5	5	
OL	Frequency	10		5	10		MHz
		15		5.5	11		
t <sub>W</sub>	Minimum Clock Pulse	5			100	200	
	Width	10			45	90	ns
		15			30	60	
t <sub>r</sub> , t <sub>f</sub>	Clock Input Rise or Fall	5					
	Time	10		, l	unlimite	d	μs
		15					
t <sub>setup</sub>	Data Setup Time Minimum	5			115	230	
	Clock Inhibit	10			50	100	ns
		15			35	75	
RESET O	PERATION						
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay Time	5			265	530	
	(carry out or decoded out	10			115	230	ns
	lines)	15			85	170	
t <sub>W</sub>	Minimum Reset Pulse	5			130	260	
	Width	10			55	110	ns
		15			30	60	
t <sub>REM</sub>	Minimum Reset Removal	5			200	400	
	Time	10			140	280	ns
		15			75	150	

<sup>(\*)</sup> Typical temperature coefficient for all V<sub>DD</sub> value is 0.3 %/°C. (1) Measured with respect to carry out line.

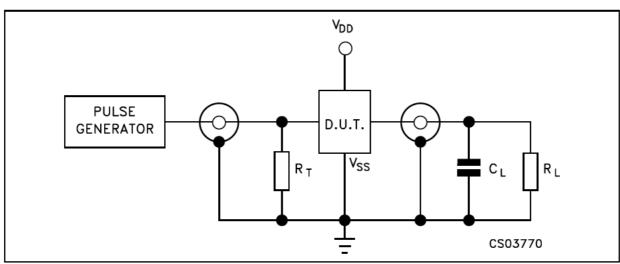
#### **TYPICAL APPLICATIONS**

DIVIDE BY N COUNTER(N < 10) WITH **DECODED OUTPUTS** 



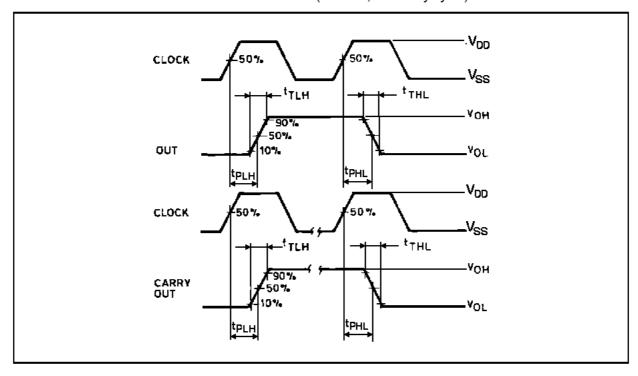
When the Nth decoded output is reached (Nth clock pulse) the S-R flip-flop (constructed from two NOR gates of the HCF4001B) generates a reset pulse which clears the HCF4017B to its zero count. At this time, if the Nth decoded output is greater than or equal to 6, the COLIT line goes high to clock the next HCF4017B counter section. The "0" decoded output also goes high at this time. Coincidence of the clock low and decoded "0" output high resets the S-R flip-flop to enable the HCF4017B. If the N<sup>th</sup> decoded output is less than 6, the COUT line will not go high and, therefore, cannot be used. In this case "0" decoded output may be used to perform the clocking function for the next counter.

#### **TEST CIRCUIT**

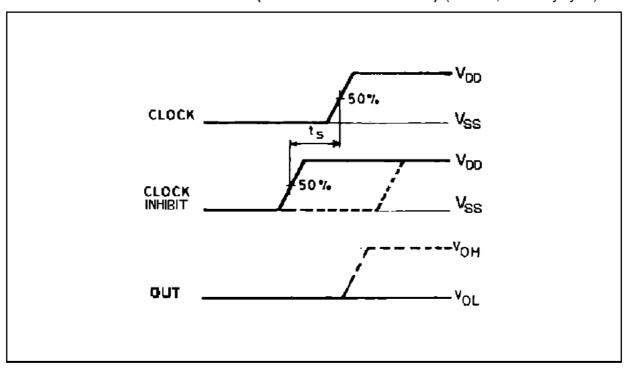


 $C_L$  = 50pF or equivalent (includes jig and probe capacitance)  $R_L$  = 200K $\Omega$   $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

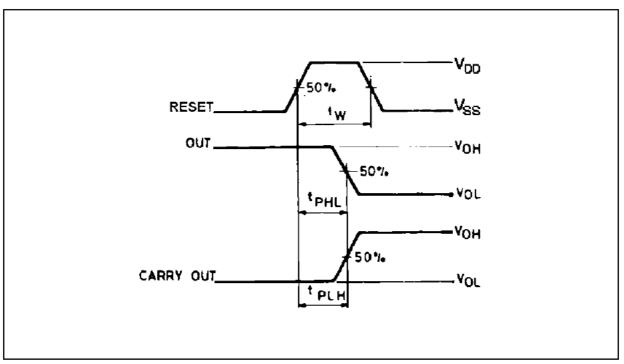
WAVEFORM 1: PROPAGATION DELAY TIMES (f=1MHz; 50% duty cycle)



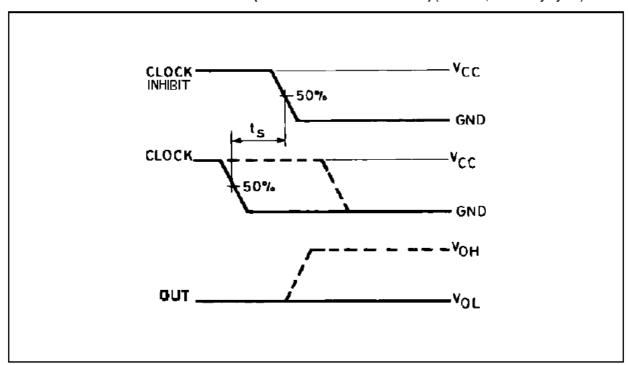
WAVEFORM 2: MINIMUM SETUP TIME (CLOCK INHIBIT TO CLOCK) (f=1MHz; 50% duty cycle)



WAVEFORM 3: PROPAGATION DELAY TIMES, MINIMUM RESET PULSE WIDTH ( f= 1 MHz; 50% duty cycle)

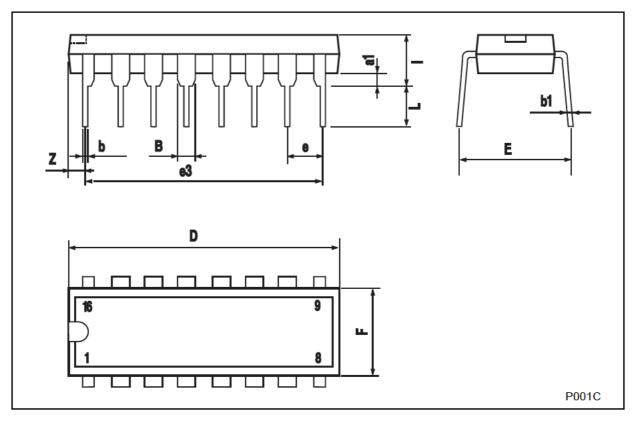


WAVEFORM 4: MINIMUM SETUP TIME (CLOCK TO CLOCK INHIBIT) (f=1MHz; 50% duty cycle)



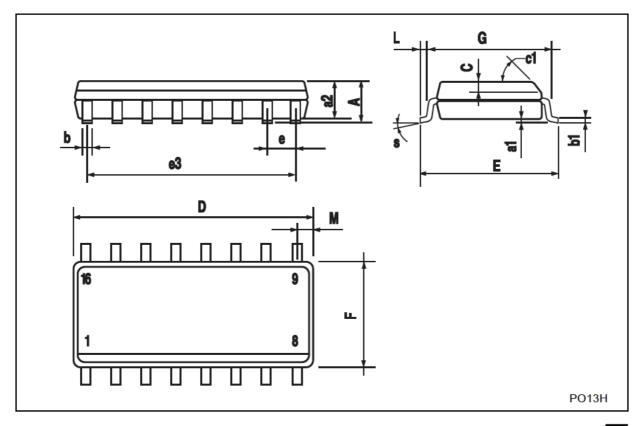
# Plastic DIP-16 (0.25) MECHANICAL DATA

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
a1	0.51			0.020				
В	0.77		1.65	0.030		0.065		
b		0.5			0.020			
b1		0.25			0.010			
D			20			0.787		
E		8.5			0.335			
е		2.54			0.100			
<b>e</b> 3		17.78			0.700			
F			7.1			0.280		
I			5.1			0.201		
L		3.3			0.130			
Z			1.27			0.050		



## **SO-16 MECHANICAL DATA**

DIM		mm.		inch				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.		
Α			1.75			0.068		
a1	0.1		0.2	0.003		0.007		
a2			1.65			0.064		
b	0.35		0.46	0.013		0.018		
b1	0.19		0.25	0.007		0.010		
С		0.5			0.019			
c1			45°	(typ.)				
D	9.8		10	0.385		0.393		
E	5.8		6.2	0.228		0.244		
е		1.27			0.050			
<b>e</b> 3		8.89			0.350			
F	3.8		4.0	0.149		0.157		
G	4.6		5.3	0.181		0.208		
L	0.5		1.27	0.019		0.050		
М			0.62			0.024		
S		•	8° (ı	max.)	•	•		



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